

BA157 thru BA159

Vishay General Semiconductor

Fast Switching Plastic Rectifier

Major Ratings and Characteristics

I _{F(AV)}	1.0 A			
V _{RRM}	50 V to 600 V			
I _{FSM}	20 A			
t _{rr}	150 ns, 250 ns, 500 ns			
I _R	5.0 μA			
V _F	1.3 V			
T _j max.	125 °C			

Features

- Fast switching for high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- Solder Dip 260 °C, 40 seconds

Typical Applications

For use in fast switching rectification of power supply, inverters, converters and freewheeling diodes for consumer and Telecommunication.

(Note: These devices are not Q101 qualified. Therefore, the devices specified in this datasheet have not been designed for use in automotive or Hi-Rel applications.)

Maximum Ratings

(T_A = 25 °C unless otherwise noted)

Parameter	Symbol	BA157	BA158	BA159D	BA159	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	400	600	800	1000	V
Maximum average forward rectified current 0.375" (9.5 mm) lead length at $\rm T_A$ = 55 $^{\circ}\rm C$	I _{F(AV)}	1.0				A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	20				A
Maximum operation junction temperature	ТJ	- 65 to + 125				°C
Maximum storage temperature	T _{STG}	- 65 to + 150				°C



Mechanical Data

Case: DO-204AL, molded epoxy body Epoxy meets UL-94V-0 Flammability rating Terminals: Matte tin plated (E3 Suffix) leads, solderable per J-STD-002B and JESD22-B102D Polarity: Color band denotes cathode end



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Electrical Characteristics

(T_A = 25 °C unless otherwise noted)

Parameter	Test condition	Symbol	BA157	BA158	BA159D	BA159	Unit
Maximum instantaneous forward voltage	at 1.0 A	V _F	1.3				V
Maximum DC reverse current at rated DC blocking voltage	T _A = 25 °C	I _R	5.0				μΑ
Maximum reverse recovery time	at $I_F = 0.5 \text{ A}$, $I_R = 1.0 \text{ A}$, $I_{rr} = 0.25 \text{ A}$	t _{rr}	150	250	50	00	ns
Typical junction capacitance	at 4.0 V, 1 MHz	CJ	12				pF

Ratings and Characteristics Curves

 $(T_A = 25 \degree C \text{ unless otherwise noted})$

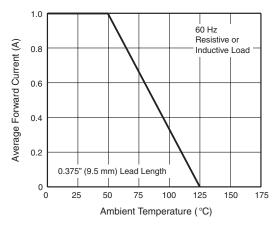


Figure 1. Forward Current Derating Curve

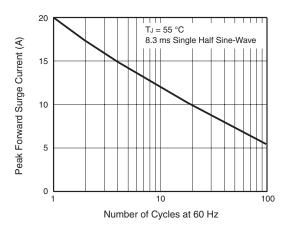


Figure 2. Maximum Non-repetitive Peak Forward Surge Current

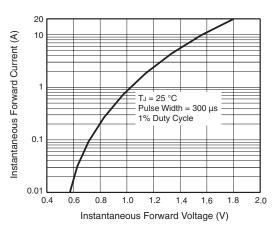


Figure 3. Typical Instantaneous Forward Characteristics

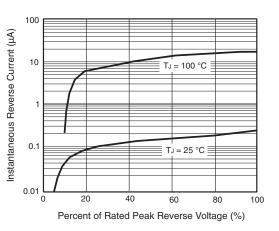
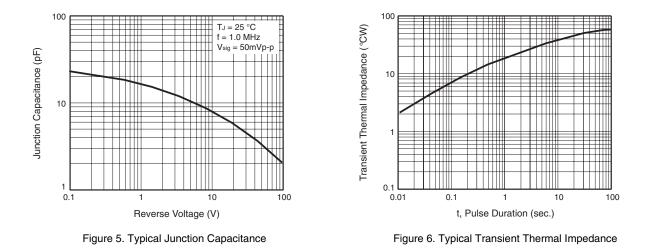


Figure 4. Typical Reverse Characteristics

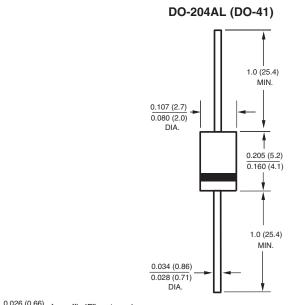


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Package outline dimensions in inches (millimeters)



NOTE: Lead diameter is $\frac{0.026 (0.66)}{0.023 (0.58)}$ for suffix "E" part numbers



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